COMPLIANT



Low Power, High Voltage SPST Analog Switches

DESCRIPTION

The DG447 and DG448 are dual supply single-pole/single-throw (SPST) switches. On resistance is 25 Ω maximum and flatness is 2.2 Ω max over the specified analog signal range. These analog switches were designed to provide high speed, low error switching of precision analog signals. The primary application areas are in the routing and switching in telecommunications and test equipment. Combining low power, low leakages, low on-resistance and small physical size, the DG477/448 are also ideally suited for portable and battery powered industrial and military equipment.

The DG477 has one normally closed switch, while the DG448 switch is normally open. They operate either from a single + 7 V to 36 V supply or from dual \pm 4.5 V to \pm 20 V supplies. They are offered in the very popular, small T6SOP6 package.

FEATURES

- ± 15 V Analog Signal Range
- On-Resistance $r_{DS(on)}$: 25 Ω max
- Fast Switching Action T_{ON}: 100 ns
- V_L Logic Supply Not Required
- TTL CMOS Input Compatible
- Rail To Rail Signal Handling
- Dual Or Single Supply Operation

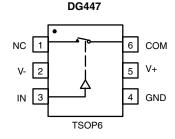
BENEFITS

- · Wide Dynamic Range
- · Low Signal Errors and Distortion
- · Break-Before-Make Switching Action
- · Simple Interfacing
- Reduced Board Space
- Improved Reliability

APPLICATIONS

- · Precision Test Equipment
- · Precision Instrumentation
- · Communications Systems
- PBX, PABX Systems
- · Audio Equipment
- Redundant Systems
- PC Multimedia Boards
- Hard Disc Drives

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



_	• \	_	
NO 1	ا ا	6	COM
	 	\neg	V.
V- 2		5	V+
IN 3	<u> </u>	_	CND
IN 3	1	4	GND
	T0000		
	TSOP6		

DG448

TRUTH TABLE					
Logic	DG447	DG448			
0	ON	OFF			
1	OFF	ON			

Logic "0" \leq 0.8 V Logic "1" \geq 2.4 V

Device Marking: DG447DV = G5xxx DG448DV = G6xxx



ORDERING INFORMATION					
Temp Range	Package	Part Number			
DG447/DG448					
- 40 to 85 °C	6-Pin TSOP	DG447DV-T1-E3			
	0-FIII 130F	DG448DV-T1-E3			

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter Referenced To V-		Symbol	Limit	Unit		
V+			44			
GND			25	V		
Digital Inputs ^a , V _{no/nc} , V _{COM}			(V-) - 2 V to (V+) + 2 V or 30 mA, whichever occurs first]		
Current , (Any Terminal) Continuous			30	mA		
Current (NO or NC or COM) Pulsed at 1 ms, 10 % duty cycle			100	IIIA		
Storage Temperature			- 65 to 150	°C		
Power Dissipation (Package) ^b	6-Pin TSOP ^c		570	mW		

Notes:

- a. Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 7 mW/°C above 70 °C.



DG447/448 Vishay Siliconix

		Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V	e Specified	D Suffix - 40 to 85 °C			
Parameter	Symbol	$V_{IN} = 15 \text{ V}, V_{I} = -15 \text{ V}$ $V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^{f}$	Temp ^b	Min ^d	Typ ^c	Max ^d	Unit
Analog Switch	-					L	
Analog Signal Range ^e	V _{ANALOG}		Full	- 15		15	V
Drain-Source On-Resistance	r _{ON}	$I_{\text{no/nc}} = 10 \text{ mA}, V_{\text{COM}} = 10 \text{ V}$ V+ = 13.5 V, V- = -13.5 V	Room Full		17	25 30	Ω
On-Resistance Flatness	r _{ON} Flatness	$I_{\text{no/nc}} = 10 \text{ mA}, V_{\text{COM}} = \pm 5 \text{ V}, 0 \text{ V}$ V+ = 13.5 V, V- = -13.5 V	Room Full		0.8	2.2 3	52
Switch Off Leakage Current	I _{no/nc(off)}	V+ = 16.5, V- = - 16.5 V V _{COM} = ± 15.5 V	Room Full	- 1 - 10	- 0.1	1 10	
	I _{COM(off)}	$V_{\text{no/nc}} = -/+ 15.5 \text{ V}$	Room Full	- 1 - 10	- 0.1	1 10	nA
Channel On Leakage Current	I _{COM(on)}	V+ = 16.5 V, V- = -16.5 $V_{COM} = V_{no/nc} = \pm 15.5 \text{ V}$	Room Full	- 1 - 10	- 0.1	1 10	
Digital Control					•		
Input, High Voltage	I _{INH}		Full	2.4			V
Input, Low Voltage	I _{INL}		Full			0.8	V
Input Capacitance ^e	C _{IN}		Room		5		pF
Input Current	I _{IN}	$V_{IN} = 0 \text{ or } 5 \text{ V}$		- 1		1	μA
Dynamic Characteristics							
Turn-On Time	t _{ON}	$R_L = 300 \Omega$, $C_L = 35 pF$	Room Full		100	130 140	ns
Turn-Off Time	t _{OFF}	$V_{no/nc} = \pm 10 \text{ V}$	Room Full		50	95 110	110
Charge Injection ^e	Q	$C_L = 1 \text{ nF, } V_{gen} = 0 \text{ V, } R_{gen} = 0 \Omega$	Room		2		рС
Off-Isolation ^e	OIRR	C_L = 5 pF, R_L = 50 Ω , f = 1 MHz	Room		- 72		dB
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room		19		
Drain Off Capacitance ^e	C _{D(off)}	I = I IVIDZ	Room		8		рF
Channel On Capacitance ^e	C _{D(on)}	f = 1 MHz	Room		30		
Power Supplies	- 1				•	•	
Positive Supply Current	I+	V+ = 16.5 V, V- = - 16.5 V	Room Full		16	30 50	μA
Negative Supply Current	I-	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full	- 1 - 10	- 0.02		μΑ



SPECIFICATIONS ^a							
		Test Conditions Unless Otherwise Specified		D Suffix - 40 to 85 °C			
Parameter	Symbol	V+ = 12 V, V- = 0 V $V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp ^b	Min ^d	Тур ^с	Max ^d	Unit
Analog Switch	1 0,				- 76	1	J
Analog Signal Range ^e	V _{ANALOG}		Full	0		12	V
Drain-Source On-Resistance	r _{ON}	$I_{\text{no/nc}} = -10 \text{ mA}, V_{\text{COM}} = 8 \text{ V}$ V+ = 10.8 V	Room Full		32	45 60	Ω
On-Resistance Flatness	r _{ON} Flatness	I _{no/nc} = 10 mA, V _{COM} = 2, 6, 8 V V+ = 10.8 V	Room Full		2	6 8	Ω
Dynamic Characteristics	Dynamic Characteristics						
Turn-On Time	t _{ON}	$V_{NO, NC} = \pm 10 \text{ V}, R_L = 300 \Omega, C_L = 35 \text{ pF}$	Room Full		140	175 225	nS
Turn-Off Time	t _{OFF}	VNO, NC = ± 10 V, HL = 300 22, OL = 33 PI	Room Full		50	120 150	110
Charge Injection ^e	Q	C_L = 10 nF, V_{gen} = 0 V, R_{gen} = 0 Ω	Room		10		рC
Power Supplies							
Positive Supply Current	l+	V+ = 13.2 V, V _{IN} = 0 V, 5 V	Room Full		22	50 75	μΑ

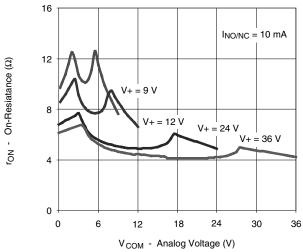
Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

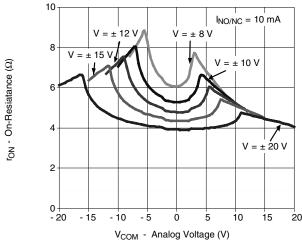
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



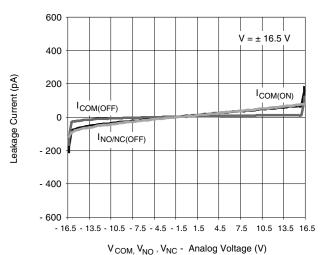
TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



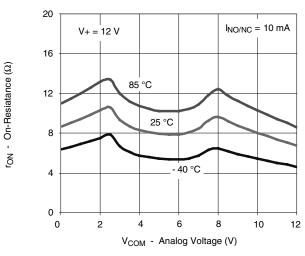
 $r_{\mbox{\scriptsize ON}}$ vs. $V_{\mbox{\scriptsize COM}}$ and Single Supply Voltage



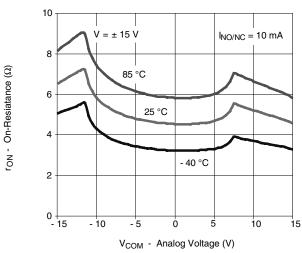
 $r_{\mbox{\scriptsize ON}}$ vs. $V_{\mbox{\scriptsize COM}}$ and Dual Supply Voltage



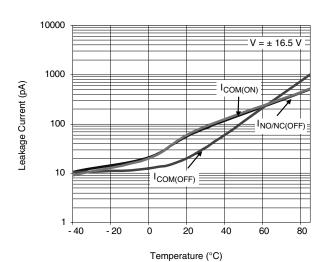
Leakage vs. Analog Voltage



r_{ON} vs. Analog Voltage and Temperature

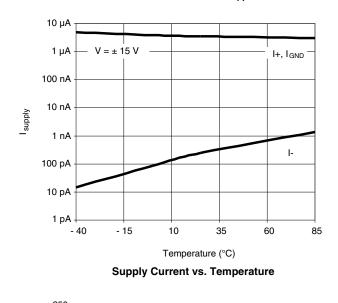


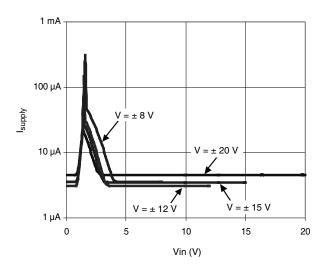
r_{ON} vs. Analog Voltage and Temperature



Leakage Current vs. Temperature

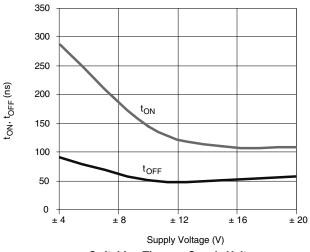
TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted

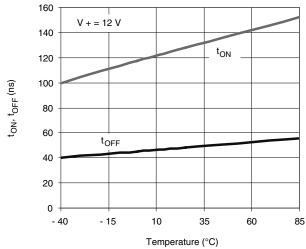




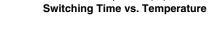


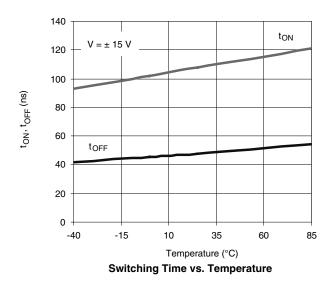
Supply Current vs. V_{IN}

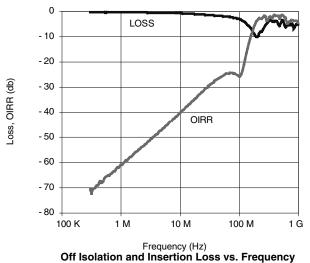




Switching Time vs. Supply Voltages

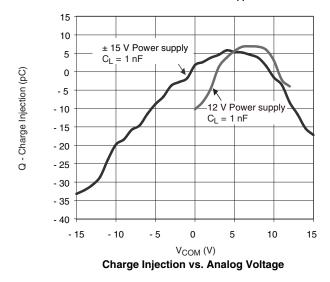


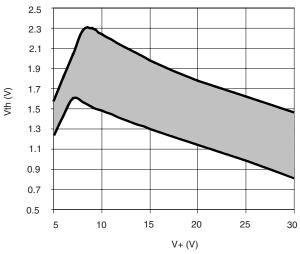






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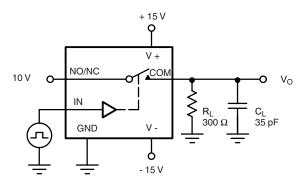




Input Switching Threshold vs. Supply Voltage

TEST CIRCUITS

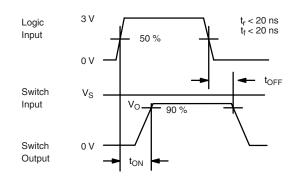
V_O is the steady state output with the switch on.



C_L (includes fixture and stray capacitance)

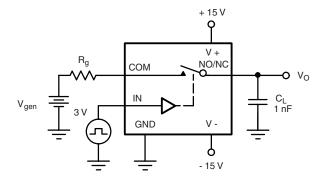
$$V_O = V_S$$

$$\frac{R_L}{R_L + r_{ON}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

Figure 1. Switching Time



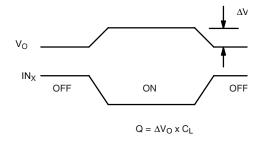


Figure 2. Charge Injection

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TEST CIRCUITS

V_O is the steady state output with the switch on.

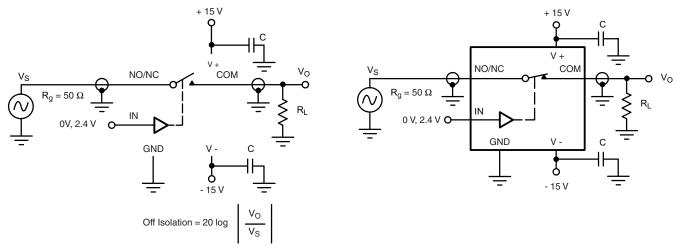


Figure 3. Off Isolation

Figure 4. Insertion Loss

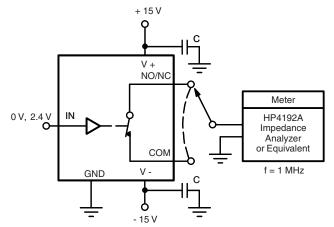


Figure 5. Source/Drain Capacitances

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